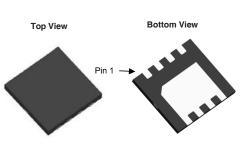


## P-Channel 12 V (D-S) MOSFET

PRODUCT SUMMARY						
V <sub>DS</sub> (V)	<b>R<sub>DS(on)</sub> (</b> Ω <b>)</b>	I <sub>D</sub> (A) <sup>a</sup>	Q <sub>g</sub> (Typ.)			
	0.0098 at V <sub>GS</sub> = - 4.5 V	- 23.5				
- 12	0.015 at V <sub>GS</sub> = - 2.5 V	- 15.2	35 nC			
	0.02/ at V <sub>GS</sub> = - 1.8 V	- 10.5				



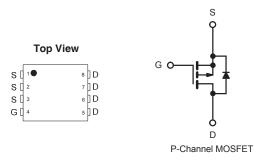
#### DFN 3x3 EP

#### **FEATURES**

- DT-Trench Power MOSFET
- Ultra Small DFN3x3 Chipscale ٠ Packaging Reduces Footprint Area, Profile (0.62 mm) and On-Resistance Per Footprint Area
- ٠ Compliant to RoHS Directive 2002/95/EC

### **APPLICATIONS**

- · PA Switch
- Battery Switch
- Load Switch •



<b>ABSOLUTE MAXIMUM RATING</b>	<b>S</b> (T <sub>A</sub> = 25 °C, unle	ess otherwise n	oted)		
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage	V <sub>DS</sub>	- 12	V		
Gate-Source Voltage	V <sub>GS</sub>	± 8	v		
	T <sub>C</sub> = 25 °C		- 23.5		
Continuous Drain Current (T <sub>J</sub> = 150 °C)	T <sub>C</sub> = 70 °C		- 26.7		
	T <sub>A</sub> = 25 °C	I <sub>D</sub>	- 20.7 <sup>b, c</sup>		
	T <sub>A</sub> = 70 °C		- 08.7 <sup>b, c</sup>	А	
Pulsed Drain Current		I <sub>DM</sub>	- 105		
Continuous Source-Drain Diode Current	T <sub>C</sub> = 25 °C	L	- 16.7		
Continuous Source-Drain Diode Current	T <sub>A</sub> = 25 °C	I <sub>S</sub>	- 3.5 <sup>b, c</sup>		
	T <sub>C</sub> = 25 °C		37		
Maximum Dawar Dissinction	T <sub>C</sub> = 70 °C	P <sub>D</sub>	26	w	
Maximum Power Dissipation	T <sub>A</sub> = 25 °C	F D	2.9 <sup>b, c</sup>	vv	
	T <sub>A</sub> = 70 °C		1.96 <sup>b, c</sup>		
Operating Junction and Storage Temperature Ra	T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150	°C		
Package Reflow Conditions <sup>d</sup> IR/Convection			260		

Notes:

a. Based on T<sub>C</sub> = 25 °C.
b. Surface mounted on 1" x 1" FR4 board.

c. t = 10 s.

d. Refer to IPC/JEDEC (J-STD-020), no manual or hand soldering.

e. In this document, any reference to the Case represents the body of the DFN2X2 device and Foot is the bump.

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THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient <sup>a, b</sup>		R <sub>thJA</sub>	31	42	°C/W	
Maximum Junction-to-Foot (Drain) Steady State		R <sub>thJF</sub>	13	16	C/W	

Notes:

a. Surface mounted on 1" x 1" FR4 board.b. Maximum under steady state conditions is 72 °C/W.

arameter Symbol		Test Conditions	Min.	Тур.	Max.	Unit	
Static					1	<b>.</b>	
Drain-Source Breakdown Voltage	V <sub>DS</sub>	$V_{GS} = 0 V, I_{D} = -250 \text{ oA}$	- 12			V	
V <sub>DS</sub> Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I <sub>D</sub> = - 250 òA		- 13.3		mV/°C	
V <sub>GS(th)</sub> Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	1 <sub>D</sub> = - 250 0A		2.4			
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = -250 \text{ oA}$	- 0.75		- 0.9	V	
Gate-Source Leakage	I <sub>GSS</sub>	$V_{DS}$ = 0 V, $V_{GS}$ = 0/ V			- 100	nA	
Zara Cata Valtaga Drain Current	1	$V_{DS}$ = - 8 V, $V_{GS}$ = 0 V	- 1		۲A		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS}$ = - 8 V, $V_{GS}$ = 0 V, $T_{J}$ = 70 °C			- 10	- òA	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS}{\leq}5$ V, $V_{GS}$ = - 4.5 V	- 20			Α	
		V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 1 A		0.0/87	0.012	Ω	
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	V <sub>GS</sub> = - 2.5 V, I <sub>D</sub> = - 1 A		0.015	0.018		
		V <sub>GS</sub> = - 1.8 V, I <sub>D</sub> = - 1 A		0.020	0.024		
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	V <sub>DS</sub> = - 4 V, I <sub>D</sub> = - 1 A		8.3		S	
Dynamic <sup>b</sup>						•	
Input Capacitance	C <sub>iss</sub>			2220		pF	
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ = - 6 V, $V_{GS}$ = 0 V, f = 1 MHz		865			
Reverse Transfer Capacitance	C <sub>rss</sub>			555		1	
Total Gate Charge	Qg	$V_{DS}$ = - 6 V, $V_{GS}$ = - 5 V, $I_D$ = - 1 A		38	57		
Iotal Gate Charge				35	53	nC	
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ = - 6 V, $V_{GS}$ = - 4.5 V, $I_D$ = - 1 A		7.3			
Gate-Drain Charge	Q <sub>gd</sub>			5.9			
Gate Resistance	Rg	V <sub>GS</sub> = - 0.1 V, f = 1 MHz		28		Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			14	21		
Rise Time	t <sub>r</sub>	$t_r$ $V_{DD} = -6 V, R_L = 4 \Omega$		25	40	nc	
Turn-Off Delay Time	t <sub>d(off)</sub>	$\text{I}_\text{D}\cong$ - 1 A, $\text{V}_\text{GEN}$ = - 4.5 V, $\text{R}_\text{g}$ = 6 $\Omega$		380	570	ns	
Fall Time	t <sub>f</sub>			240	360	1	

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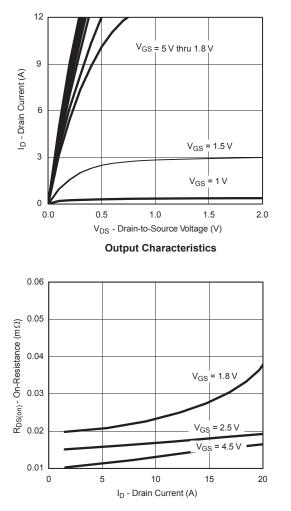
<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted							
Parameter	Symbol Test Conditions		Min.	Тур.	Max.	Unit	
Drain-Source Body Diode Characteristics							
Continuous Source-Drain Diode Current	۱ <sub>S</sub>	T <sub>C</sub> = 25 °C			- 30.5	А	
Pulse Diode Forward Current	I <sub>SM</sub>				- 105	A	
Body Diode Voltage	V <sub>SD</sub>	I <sub>S</sub> = - 1 A, V <sub>GS</sub> = 0 V		- 0.65	- 1.2	V	
Body Diode Reverse Recovery Time	t <sub>rr</sub>			311	467	ns	
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>F</sub> = - 1 A, dl/dt = 100 A/òs, T <sub>I</sub> = 25 °C		1.136	1.705	òC	
Reverse Recovery Fall Time	t <sub>a</sub>	$F = -1.7, a_{1}a_{1} = -100 \text{ Alos}, T = 20.00$		116		20	
Reverse Recovery Rise Time	t <sub>b</sub>			195		ns	

Notes:

a. Pulse test; pulse width  $\leq$  300 òs, duty cycle  $\leq$  2 %. b. Guaranteed by design, not subject to production testing.

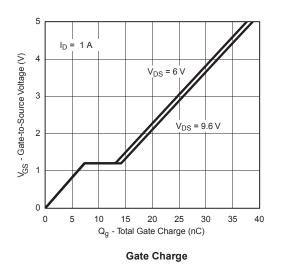
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

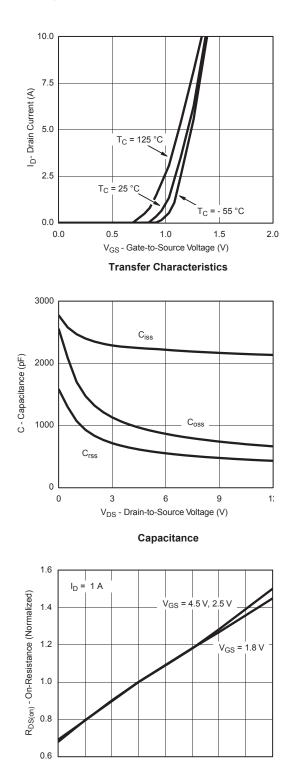




### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

On-Resistance vs. Drain Current and Gate Voltage







75 100

125 150

50

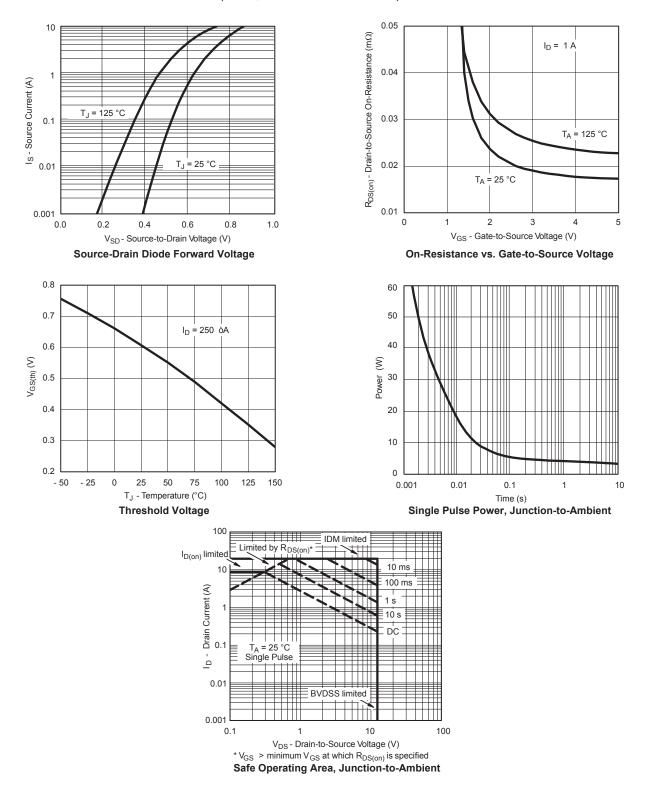
- 50 - 25

0

25

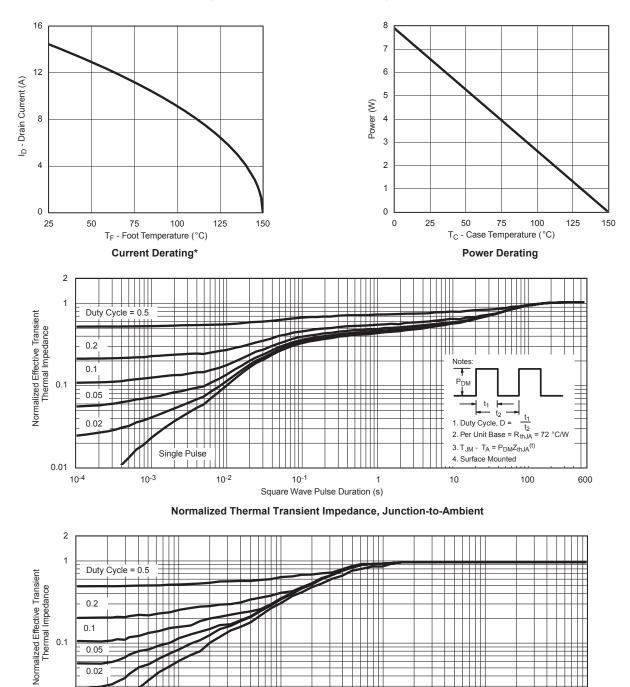


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## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





## TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Single Pulse

10<sup>-3</sup>

Square Wave Pulse Duration (s)
Normalized Thermal Transient Impedance, Junction-to-Foot

10<sup>-1</sup>

1

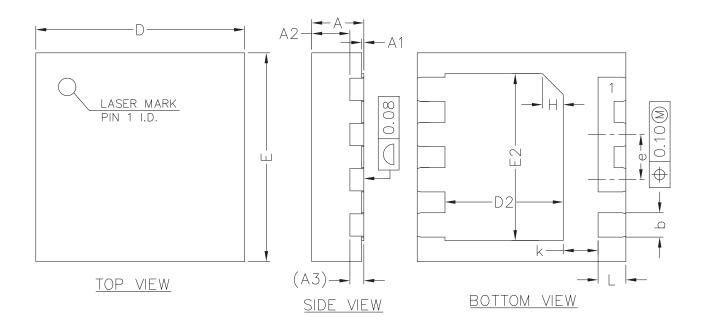
10

10<sup>-2</sup>

0.01 L 10<sup>-4</sup>



# Package Information www.din-tek.jp



<u>SIDE VIEW</u>

SYMBOL	MIN	NOM	MAX
А	0.70	0.75	0.80
A1	0.00	0.02	0.05
A2	0.50	0.55	0.60
A3		0.20REF	
b	0.30	0.35	0.40
D	2.90	3.00	3.10
E	2.90	3.00	3.10
D2	1.60	1.70	1.80
E2	2.30	2.40	2.50
е	0.55	0.65	0.75
K	0.40	0.50	0.60
L	0.35	0.40	0.45

## COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)



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